

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS . P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

DATE MAILED: 08/09/2005

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/696,186	10/29/2003	Meng-Chi Hung	252011-1730	6584
47390 7	590 08/09/2005	·	EXAMINER	
THOMAS, KAYDEN, HOSTEMEYER & RISLEY LLP			OWENS, DOUGLAS W	
100 GALLERI SUITE 1750	A PARKWAY		ART UNIT	PAPER NUMBER
ATLANTA, G	GA 30339		2811	

Please find below and/or attached an Office communication concerning this application or proceeding.

•				<u> </u>
		Application No.	Applicant(s)	
·		10/696,186	HUNG ET AL.	
	Office Action Summary	Examiner	Art Unit	
		Douglas W. Owens	2811	
Period for F	The MAILING DATE of this communication app Reply	ears on the cover sheet with	the correspondence address	
THE MA - Extension after SIX - If the perior of the period of the perior of the period	RTENED STATUTORY PERIOD FOR REPLY ALLING DATE OF THIS COMMUNICATION. Ins of time may be available under the provisions of 37 CFR 1.13 (6) MONTHS from the mailing date of this communication. In order reply specified above is less than thirty (30) days, a reply riod for reply is specified above, the maximum statutory period we or reply within the set or extended period for reply will, by statute, y received by the Office later than three months after the mailing patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a rep y within the statutory minimum of thirty ( vill apply and will expire SIX (6) MONTH , cause the application to become ABA	ly be timely filed  (30) days will be considered timely.  HS from the mailing date of this communication.  NDONED (35 U.S.C. § 133).	
Status				
2a)□ Ti 3)□ Si	esponsive to communication(s) filed on <u>31 Ja</u> nis action is <b>FINAL</b> . 2b) This ince this application is in condition for allowar osed in accordance with the practice under E	action is non-final.  nce except for formal matter	· ·	
Disposition	ı of Claims			1
4a 5)☐ Cl 6)☒ Cl 7)☒ Cl	laim(s) <u>1-69</u> is/are pending in the application.  Of the above claim(s) <u>36-69</u> is/are withdraw laim(s) is/are allowed.  laim(s) <u>1,4,11,23,24 and 29-35</u> is/are rejected laim(s) <u>2,3,5-10,12-22 and 25-28</u> is/are object laim(s) are subject to restriction and/or	vn from consideration. d. eted to.		
Application	ı Papers			
10)⊠ Th Ap Re	the specification is objected to by the Examine the drawing(s) filed on 29 October 2003 is/are: oplicant may not request that any objection to the deplacement drawing sheet(s) including the correct the oath or declaration is objected to by the Examine	: a)⊠ accepted or b)⊡ obj drawing(s) be held in abeyanc tion is required if the drawing(s	e. See 37 CFR 1.85(a). ) is objected to. See 37 CFR 1.121(d)	).
Priority und	der 35 U.S.C. § 119		•	
a) 1. 2. 3.	knowledgment is made of a claim for foreign  All b) Some * c) None of:  Certified copies of the priority documents  Copies of the certified copies of the priority documents  application from the International Bureau the attached detailed Office action for a list	s have been received. s have been received in Ap rity documents have been re u (PCT Rule 17.2(a)).	plication No eceived in this National Stage	
Attachment(s)	) of References Cited (PTO-892)	4) 🗍 Interview Su	mmary (PTO-413)	
2) Notice of 3) Informat	of Draftsperson's Patent Drawing Review (PTO-948) tion Disclosure Statement(s) (PTO-1449 or PTO/SB/08) lo(s)/Mail Date <u>10/29/03</u> .	Paper No(s)/	Mail Date  primal Patent Application (PTO-152)	

Art Unit: 2811

### **DETAILED ACTION**

## Election/Restrictions

1. Applicant's election of the first embodiment, claims 1 – 35 in the reply filed on January 31, 2005 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

## Claim Objections

2. Claim 3 is objected to because of the following informalities: Claim 3 draws reference to multiple bonding pad structures. There is no antecedent basis for such limitations since the previous claims only recite a single bond pad structure.

Appropriate correction is required.

#### Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 4. Claims 1, 4, 5, 9 11, 23, 24, 29 and 33 35 are rejected under 35
- U.S.C. 102(b) as being anticipated by US Patent No. 6,426,555 to Hsia et al.

Regarding claim 1, Hsia et al. teach a bonding pad structure, (Figs. 5 – 9) comprising:

a substrate having a bonding region and a sensing region (Col. 1, lines 53 – 56; the sensing region would be required for the electrical probing);

Application/Control Number: 10/696,186

Art Unit: 2811

a first dielectric layer (15) overlying the substrate and having a dielectric island surrounded by a ring-shaped trench (91);

a first conductive layer (54) formed in the ring-shaped trench of the first dielectric layer;

a passivation layer (42-44) formed overlying the first dielectric layer and having an opening, wherein the opening corresponds to the bonding region and the sensing region and exposes the dielectric island and a part of the first conductive layer; and

a second conductive layer (33) covering the opening of the passivation layer and electrically connected to the first conductive layer.

Regarding claim 4, Hsia et al. teach a bonding pad structure, wherein the width of the first conductive layer is with the range of 1 - 50 microns (Col. 2, lines 55 - 57).

Regarding claim 5, Hsia et al. teach a bonding pad structure, wherein the depth of the first conductive layer is within the range of 0.5 - 2 microns (Col. 2, lines 55 - 57).

Regarding claim 9, Hsia et al. teach a bonding pad structure, wherein the trench of the first dielectric layer is a quadrilateral ring.

Regarding claim 10, Hsia et al. teach a bonding pad structure, wherein the first conductive layer is a quadrilateral ring.

Regarding claim 11, Hsia et al. teach a bonding pad structure, wherein the second conductive layer is a quadrilateral solid.

Regarding claim 23, Hsia et al. teach a bonding pad structure, further comprising:

Application/Control Number: 10/696,186

Art Unit: 2811

an extension portion of the first conductive layer extending away from the bonding region and the sensing region (the conductive layer extends away from these regions); and

a circuit under pad scheme formed underlying the extension portion of the first conductive layer (Col. 2, lines 50 - 55).

Regarding claim 24, Hsia et al. teach a bonding pad structure, wherein the CUP scheme comprises:

a circuit scheme formed underlying the extension portion of the first conductive layer; and

Hsia et al. inherently teach a plurality of conductive plugs electrically connecting the circuit scheme to the extension portion of the first conductive layer, since the connection is required for communication with the circuit.

Regarding claim 29, Hsia et al. inherently teach a bonding element overlying the second conductive layer within the bonding region, since that is the purpose of a bonding pad.

Regarding claim 33, Hsia et al. teach a bonding pad structure, wherein the first conductive layer is copper, AlCu alloy or a copper manganese alloy (Col. 3, lines 2 – 6).

Regarding claim 34, Hsia et al. teach a bonding pad structure, wherein the second conductive layer is aluminum (Col. 3, lines 50 – 58).

Regarding claim 35 Hsia et al. teach a bonding pad structure, wherein the first dielectric layer is fluorinated silicon glass, a low-k dielectrics or silicon-based dielectrics.

Application/Control Number: 10/696,186 Page 5

Art Unit: 2811

# Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims 30 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hsia et al. as applied to claims 1 29 above, and further in view of US Patent No. 4,341,594 to Carlson et al.

Regarding claim 30, Hsia et al. do not teach a bonding pad structure, wherein the bonding element is a conductive ball or conductive bump. Carlson et al. teach a bonding pad structure, wherein the bonding element is a conductive bump (18). The conductive bump is commonly used in the art with bonding pads. It would have been obvious to one having ordinary skill in the art to incorporate the teaching of Carlson et al. into the device taught by Hsia et al., since it is desirable to form structures that have art recognized reliability.

Regarding claims 31 and 32, Hsia et al. do not teach a barrier layer comprising Ti, TiN, W, WN, Ta or TaN between the first and second conductive layers. Carlson et al. teach a Ti barrier layer between conductive layers (Col. 2, lines 61 – 64). It would have been obvious to one of ordinary skill in the art at the time the invention was made to incorporate the teaching of Carlson et al. into the device taught by Hsia et al., since it is desirable to prevent unwanted diffusion between structures of the device.

# Allowable Subject Matter

Page 6

7. Claims 2, 6 – 8, 12 – 22 and 25 – 28 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Douglas W. Owens whose telephone number is 571-272-1662. The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Steven H. Loke can be reached on 571-272-1657. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Douglas W Owens

Dongt & Ome

Examiner

Art Unit 2811